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N-Channel 200 V (D-S) 175 °C MOSFET

DESCRIPTION

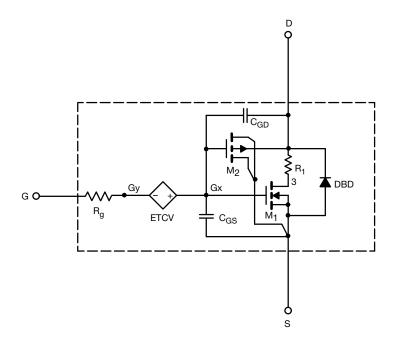
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over -55 °C to +125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- N-channel vertical DMOS
- Macro model (subcircuit model)
- Level 3 MOS
- · Apply for both linear and switching application
- Accurate over -55 °C to +125 °C temperature range
- · Model the gate charge

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.





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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	3	-	V
Drain-Source On-State Resistance a	R _{DS(on)}	V _{GS} = 10 V, I _D = 15 A	0.0186	0.0180	Ω
		$V_{GS} = 7.5 \text{ V}, I_D = 10 \text{ A}$	0.0200	0.0188	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 15 A	33	37	S
Diode Forward Voltage	V_{SD}	I _F = 12 A	0.80	0.85	V
Dynamic ^b					
Input Capacitance	C _{iss}	V _{DS} = 100 V, V _{GS} = 0 V, f = 1 MHz	1940	1950	pF
Output Capacitance	Coss		166	170	
Reverse Transfer Capacitance	C _{rss}		14	15	
Total Gate Charge	Q_g	V _{DS} = 100 V, V _{GS} = 10 V, I _D = 15 A	31	31.6	nC
Gate-Source Charge	Q _{gs}		8.6	8.6	
Gate-Drain Charge	Q_{gd}		7.6	7.6	

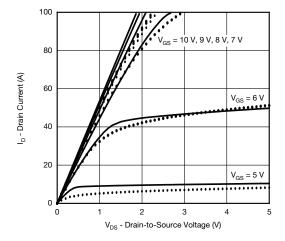
Notes

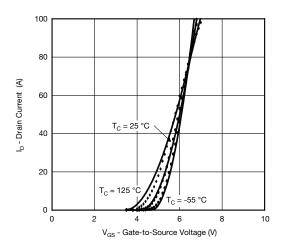
- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

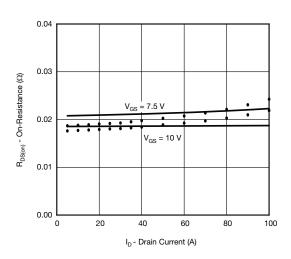
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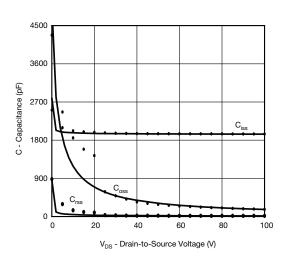
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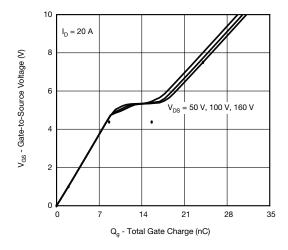
COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C, unless otherwise noted)

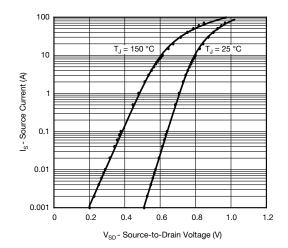












Note

• Dots and squares represent measured data.

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